# RD74LVC244B

# Octal Buffers / Line Drivers with 3-state Outputs

REJ03D0220-0200 Rev.2.00 Feb. 17, 2005

# Description

The RD74LVC244B has eight line drivers with three state outputs in a 20 pin package. This device is a non-inverting buffer and has two active low enables ( $1\overline{G}$  and  $2\overline{G}$ ). Each enable independently controls four buffers. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

# Features

- $V_{CC} = 1.65 \text{ V}$  to 5.5 V
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V to 5.5 V)
- All outputs  $V_{OUT}$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V or output off state)
- Typical V<sub>OL</sub> ground bounce < 0.8 V (@V<sub>CC</sub> = 3.3 V, Ta = 25°C)
- Typical V<sub>OH</sub> undershoot > 2.0 V (@V<sub>CC</sub> = 3.3 V, Ta =  $25^{\circ}$ C)
- High output current  $\pm 4 \text{ mA} (@V_{CC} = 1.65 \text{ V})$ 
  - $\begin{array}{l} \pm 8 \text{ mA } (@V_{CC} = 2.3 \text{ V}) \\ \pm 12 \text{ mA } (@V_{CC} = 2.7 \text{ V}) \\ \pm 24 \text{ mA } (@V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}) \end{array}$
- Ordering Information

Part Name	Package Type	Package Code	Package	Taping Abbreviation
		(Previous Code) Abbreviation		(Quantity)
RD74LVC244BFPEL	SOP–20 pin (JEITA)	PRSP0020DD-B (FP-20DAV)	FP	EL (2,000 pcs/reel)
RD74LVC244BTELL	TSSOP-20 pin	PTSP0020JB–A (TTP–20DAV)	Т	ELL (2,000 pcs/reel)

# **Function Table**

Inp		
G	А	Output Y
Н	Х	Z
L	Н	Н
L	L	L

H: High level

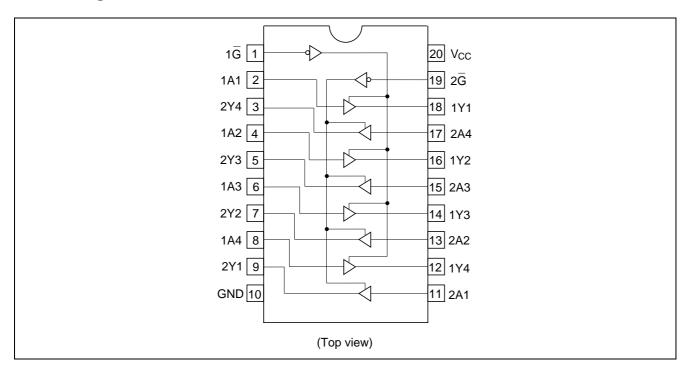
L: Low level

X: Immaterial

Z: High impedance



# **Pin Arrangement**



# **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>CC</sub>	-0.5 to 7.0	V	
Input diode current	I <sub>IK</sub>	-50	mA	V <sub>I</sub> = -0.5 V
Input voltage	VI	-0.5 to 7.0	V	
Output diode current	Ι <sub>ΟΚ</sub>	-50	mA	V <sub>O</sub> = -0.5 V
		50		$V_{O} = V_{CC} + 0.5 V$
Output voltage	Vo	–0.5 to V <sub>CC</sub> +0.5	V	Output "H" or "L"
		-0.5 to 6.0	V	Output "Z" or V <sub>CC</sub> :OFF
Output current	lo	±50	mA	
V <sub>CC</sub> , GND current / pin	I <sub>CC</sub> or I <sub>GND</sub>	100	mA	
Storage temperature	Tstg	–65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

# **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions		
Supply voltage	V <sub>CC</sub>	1.5 to 5.5	V	Data hold		
		1.65 to 5.5		At operation		
Input / Output voltage	VI	0 to 5.5 V		<del>G</del> , A		
	Vo	0 to $V_{CC}$		Output "H" or "L"		
		0 to 5.5		Output "Z" or V <sub>CC</sub> : OFF		
Operating temperature	Та	-40 to 85	°C			
Output current	I <sub>ОН</sub>	-4	mA	V <sub>CC</sub> = 1.65 V		
		-8		$V_{CC} = 2.3 V$		
		-12		$V_{CC} = 2.7 V$		
		-24		$V_{CC} = 3.0 \text{ V} \text{ to } 5.5 \text{ V}$		
	I <sub>OL</sub>	4	mA	V <sub>CC</sub> = 1.65 V		
		8		$V_{CC} = 2.3 V$		
		12		$V_{CC} = 2.7 V$		
		24		$V_{CC} = 3.0 \text{ V} \text{ to } 5.5 \text{ V}$		
Input rise / fall time <sup>*1</sup>	t <sub>r</sub> , t <sub>f</sub>	20	ns/V	$V_{CC}$ = 1.65 V to 2.7 V		
		10		$V_{CC}$ = 3.0 V to 5.5 V		

Notes: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.



# **Electrical Characteristics**

	Symbol		Ta = -40	) to 85°C		
ltem		V <sub>cc</sub> (V)	Min Max		Unit	Test Conditions
Input voltage	V <sub>IH</sub>	1.65 to 1.95	V <sub>CC</sub> ×0.65	_	V	
		2.3 to 2.7	1.7	_		
		2.7 to 3.6	2.0	—		
		4.5 to 5.5	V <sub>CC</sub> ×0.7	—		
	VIL	1.65 to 1.95	_	V <sub>CC</sub> ×0.35	V	
		2.3 to 2.7	_	0.7		
		2.7 to 3.6	_	0.8		
		4.5 to 5.5	_	V <sub>CC</sub> ×0.3		
Output voltage	V <sub>OH</sub>	1.65 to 5.5	V <sub>CC</sub> -0.2	_	V	I <sub>OH</sub> = −100 μA
		1.65	1.2	_		I <sub>OH</sub> = -4 mA
		2.3	1.7	_		I <sub>OH</sub> = -8 mA
		2.7	2.2	_		I <sub>OH</sub> = -12 mA
		3.0	2.4	_		
		3.0	2.2	—		I <sub>OH</sub> = -24 mA
		4.5	3.8	_		
	V <sub>OL</sub>	1.65 to 5.5	_	0.2	V	I <sub>OL</sub> = 100 μA
		1.65	_	0.45		I <sub>OL</sub> = 4 mA
		2.3	_	0.7		I <sub>OL</sub> = 8 mA
		2.7	_	0.4		I <sub>OL</sub> = 12 mA
		3.0	_	0.55		I <sub>OL</sub> = 24 mA
		4.5	_	0.55		
Input current	I <sub>IN</sub>	0 to 5.5	_	±5.0	μA	$V_{IN} = 5.5 \text{ V or GND}$
Output leak current	I <sub>OFF</sub>	0	_	±5.0	μA	V <sub>IN</sub> / V <sub>OUT</sub> = 5.5 V
Off state output current	l <sub>oz</sub>	2.7 to 5.5		±5.0	μA	$V_{IN} = V_{CC}$ or GND $V_{O} = 5.5$ V or GND
Quiescent supply	I <sub>CC</sub>	2.7 to 3.6	_	±5.0	μA	V <sub>IN</sub> = 3.6 V to 5.5 V
current		2.7 to 5.5	_	5.0	1 .	$V_{IN} = V_{CC}$ or GND
	Δl <sub>CC</sub>	2.7 to 3.6	_	500	μA	$V_{IN}$ = one input at (V <sub>CC</sub> -0.6)V, other inputs at V <sub>CC</sub> or GNI



# Switching Characteristics

	Ta = -40 to 85°C						From	То
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Мах	Unit	(Input)	(Output)
Propagation delay time	t <sub>PLH</sub>	1.8±0.15	1.0	_	10.9	ns	A	Y
	t <sub>PHL</sub>	2.5±0.2	1.0	_	7.9			
		2.7	1.0	_	6.9			
		3.3±0.3	1.5	_	5.9			
		5.0±0.5	1.0	_	4.4			
Output enable time	t <sub>zH</sub>	1.8±0.15	1.0	_	12.6	ns	G	Y
	t <sub>ZL</sub>	2.5±0.2	1.0	_	9.6			
		2.7	1.0	_	8.6			
		3.3±0.3	1.5	_	7.6			
		5.0±0.5	1.0	_	6.1			
Output disable time	t <sub>HZ</sub>	1.8±0.15	1.0	_	12.1	ns	G	Y
	t <sub>LZ</sub>	2.5±0.2	1.0	—	7.8			
		2.7	1.0	—	6.8			
		3.3±0.3	1.5	—	6.5			
		5.0±0.5	1.0	—	5.5			
Between output pins skew*1	t <sub>OSLH</sub>	1.8±0.15	—	—	—	ns		
	t <sub>OSHL</sub>	2.5±0.2	—	—	—			
		2.7	—	—	—			
		3.3±0.3	_	_	1.0			
		5.0±0.5	—	—	1.0			
Input capacitance	CIN	3.3	_	4.0	_	pF		
Output capacitance	Co	3.3	—	8.0	_	pF		

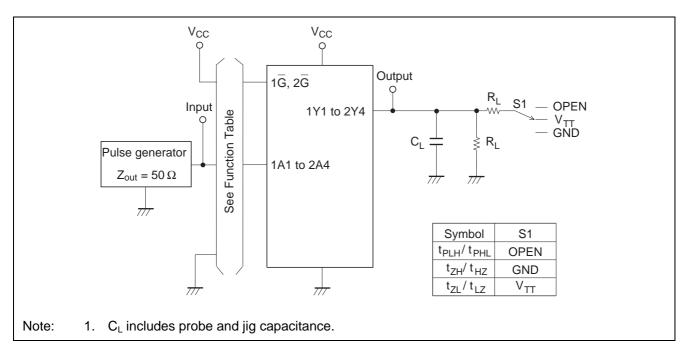
Note: 1. This parameter is characterized but not tested.

 $t_{\text{OSLH}} = \mid t_{\text{PLHm}} - t_{\text{PLHn}} \mid, t_{\text{OSHL}} = \mid t_{\text{PHLm}} - t_{\text{PHLn}} \mid$ 

# **Operating Characteristics**

			Ta = 25°C				
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	Test conditions
Power dissipation	C <sub>PD</sub>	1.8		25		pF	f = 10 MHz
Capacitance		2.5	_	25	_		
		3.3	_	27	_		
		5.0	_	32	_		

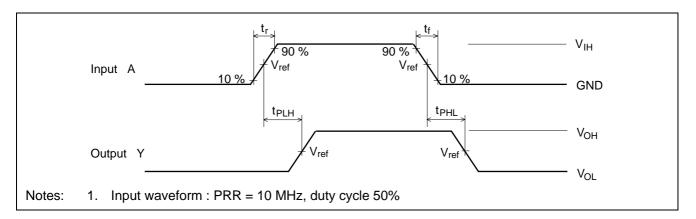
# **Test Circuit**



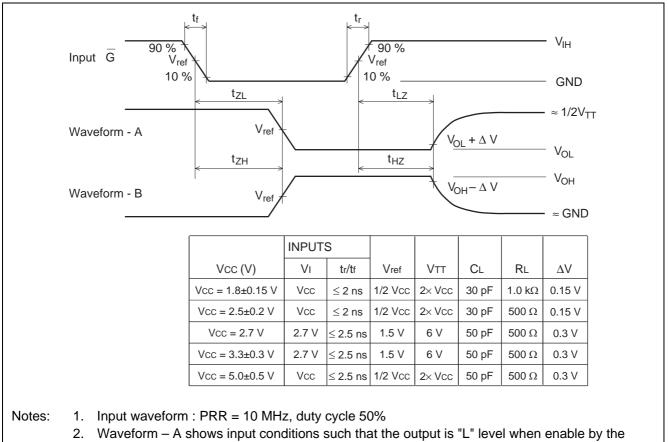


## RD74LVC244B

## Waveforms - 1



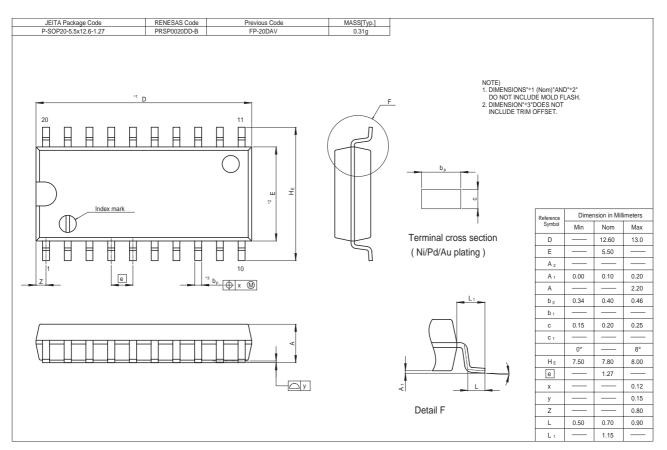
## Waveforms – 2

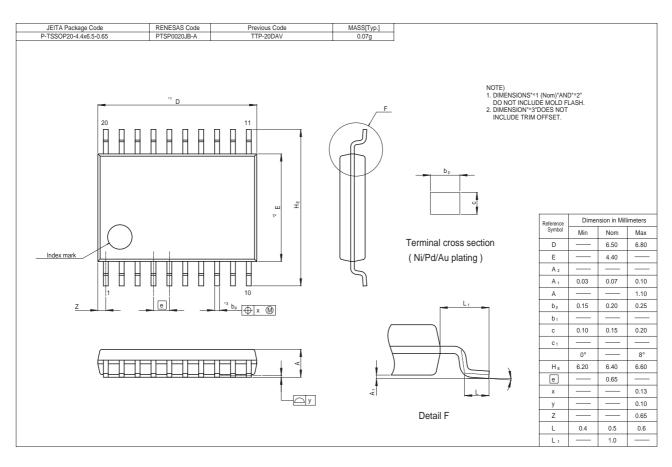


output control.

3. Waveform – B shows input conditions such that the output is "H" level when enable by the output control.

# Package Dimensions







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